



30A, 45V - 60V Trench Schottky Rectifiers

FEATURES

- Patented Trench Schottky technology
- Excellent high temperature stability
- Low forward voltage
- Low power loss/ High efficiency
- High forward surge capability
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

TYPICAL APPLICATIONS

Trench Schottky barrier rectifier is designed for high frequency miniature switched mode power supplies such as adapters, lighting and on-board DC/DC converters.

MECHANICAL DATA

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating

Packing code with suffix "G" means green compound (halogen-free) **Terminal:** Matte tin plated leads, solderable per JESD22-B102

Meet JESD 201 class 1A whisker test

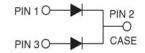
Polarity: As marked

Mounting torque: 0.56 Nm max. **Weight:** 1.88 g (approximately)









TO-220AB

| MAXIMUM RATINGS AND ELEC | TRICAL | CHARACTER | RISTICS (T _A | _ = 25°C u | nless oth | erwise no | ted) | |
|-----------------------------------------------------------------------------------------------|----------------------|------------------------|-------------------------|-----------------------|-----------|-----------|------|----|
| PARAMETER | | | SYMBOL | TST30L45CW TST30L60CW | | UNIT | | |
| Maximum repetitive peak reverse voltage | | | V_{RRM} | 45 60 | | V | | |
| Maximum average forward rectified | per device | | - I _{F(AV)} | 30 | | | | A |
| current | per diode | | | 15 | | | | |
| Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load per diode | | | I _{FSM} | 180 | | | А | |
| Voltage rate of change (Rated V _R) | | | dV/dt | 10000 | | | V/µs | |
| | | | | TYP. | MAX. | TYP. | MAX. | |
| Instantaneous forward voltage per diode (Note1) | I _F = 15A | T _J = 25°C | V _F | 0.48 | 0.55 | 0.53 | 0.60 | V |
| | I _F = 15A | T _J = 125°C | | 0.44 | 0.51 | 0.49 | 0.56 | |
| Maximum instantaneous reverse current per diode at T _J = 25°C | | | | 500 | | | | μΑ |
| rated reverse voltage | | T _J = 125°C | - I _R | 100 | | | | mA |
| Typical thermal resistance per diode | | | $R_{	heta JC}$ | 3 | | | °C/W | |
| | | | $R_{\theta JL}$ | 2 | | | | |
| Operating junction temperature range | | | T_J | - 55 to +150 | | | °C | |
| Storage temperature range | | | T _{STG} | - 55 to +150 | | | °C | |

Note 1: Pulse test with pulse width = 300µs, 1% duty cycle



| ORDERING INFORMATION | | | | | |
|----------------------|--------------|------------------------|----------|-----------|--|
| PART NO. | PACKING CODE | PACKING CODE SUFFIX | PACKAGE | PACKING | |
| TST30LXXCW | C0 | G | TO-220AB | 50 / Tube | |

Note 1: "XX" defines voltage from 45V (TST30L45CW) to 60V (TST30L60CW)

| EXAMPLE | | | | | | |
|-----------------------|------------|--------------|------------------------|----------------|--|--|
| PREFERRED PART NO. | PART NO. | PACKING CODE | PACKING CODE SUFFIX | DESCRIPTION | | |
| TST30L60CW C0G | TST30L60CW | C0 | G | Green compound | | |

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

FIG.1 FORWARD CURRENT DERATING CURVE

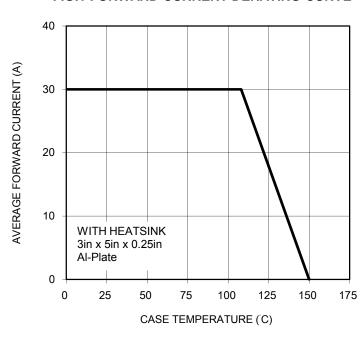


FIG.2 TYPICAL FORWARD CHARACTERISTICS

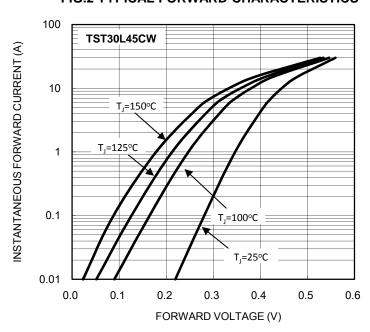


FIG.3 TYPICAL FORWARD CHARACTERISTICS

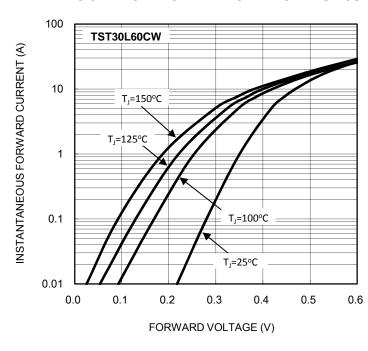


FIG.4 TYPICAL REVERSE CHARACTERISTICS

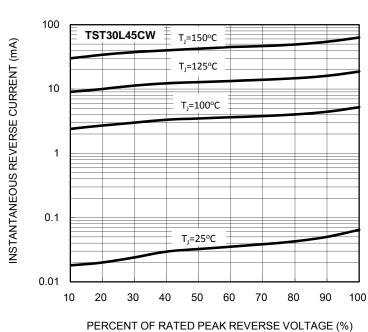




FIG.5 TYPICAL REVERSE CHARACTERISTICS

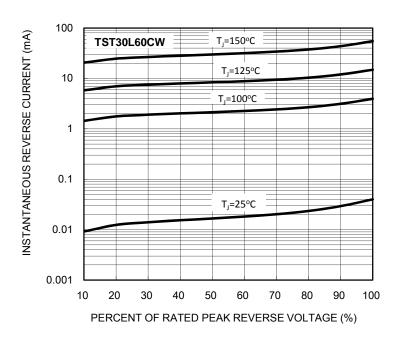
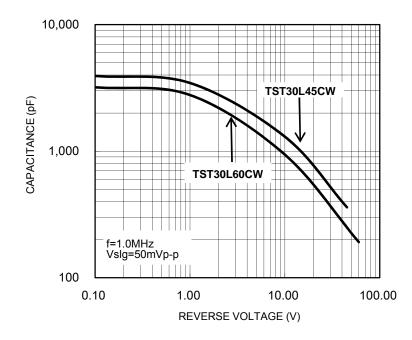
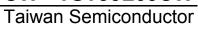


FIG.6 TYPICAL JUNCTION CAPACITANCE

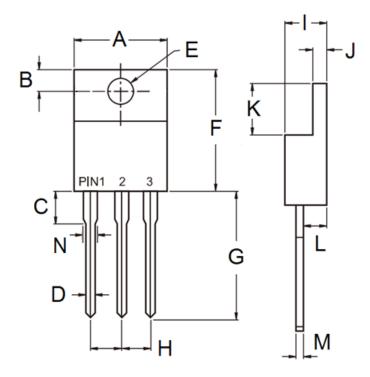






PACKAGE OUTLINE DIMENSIONS

TO-220AB



| DIM. | Unit | (mm) | Unit (inch) | | |
|--------|-------|-------|-------------|-------|--|
| Dilvi. | Min | Max | Min | Max | |
| Α | - | 10.50 | - | 0.413 | |
| В | 2.62 | 3.44 | 0.103 | 0.135 | |
| С | 2.80 | 4.20 | 0.110 | 0.165 | |
| D | 0.68 | 0.94 | 0.027 | 0.037 | |
| Е | 3.54 | 4.00 | 0.139 | 0.157 | |
| F | 14.60 | 16.00 | 0.575 | 0.630 | |
| G | 13.19 | 14.79 | 0.519 | 0.582 | |
| Н | 2.41 | 2.67 | 0.095 | 0.105 | |
| I | 4.42 | 4.76 | 0.174 | 0.187 | |
| J | 1.14 | 1.40 | 0.045 | 0.055 | |
| K | 5.84 | 6.86 | 0.230 | 0.270 | |
| L | 2.20 | 2.80 | 0.087 | 0.110 | |
| М | 0.35 | 0.64 | 0.014 | 0.025 | |

MARKING DIAGRAM



P/N = Specific Device Code G = Green Compound

YWW = Date Code

= Factory Code



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